Supporting Information for

## "Covalency-aided electrochemical mechanism for CO<sub>2</sub> reduction: synergistic effect of copper and boron dual active sites drives high-efficiency ethanol product"

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## **Computational details**

The binding energy  $(E_b)$  was calculated to estimate the strength of atom/molecule-surface interaction.  $E_b$  could be calculated by:

$$E_{\rm b} = E_{\rm system} - E_{\rm surf} - E_{\rm adsorb}$$

where  $E_{\text{system}}$ ,  $E_{\text{surf}}$ , and  $E_{\text{adsorb}}$  are the energy of adsorption structure, surface, and adsorbent, respectively.

The formation energy of B doping Cu(100) catalyst was calculated by following formula:

$$E_{\rm f} = E_{\rm B-Cu(100)} - E_{\rm Cu(100)} - \mu_{\rm B} + \mu_{\rm Cu}$$

where  $E_{B-Cu(100)}$  is the total energies of B doping at the defective Cu(100) catalyst.  $E_{Cu(100)}$  is the energy of pure Cu(100) catalyst.  $\mu_B$  and  $\mu_{Cu}$  are the chemical potentials of each B and Cu atom in bulk crystal, respectively.

The Gibbs reaction free energy change ( $\Delta G$ ) of each elementary reaction was calculated by:

$$\Delta G = \Delta E + \Delta Z P E - T \Delta S$$

where  $\Delta E$  is the reaction energy determined from DFT, and  $\Delta ZPE$  is the difference in zero-point energies due to the reaction between the adsorbed and the gas phase by setting H<sub>2</sub>O and H<sub>2</sub> in the gas phase as reference states.  $\Delta S$  is the change in entropy, computed using DFT calculations of the vibrational frequencies and standard tables for gas phase molecules. All values of  $\Delta G$ were computed at T = 298 K, and pH = 0.

The limiting potential  $(U_L)$  was calculated as  $U_L = -\Delta G_{max}/e$ , where the  $\Delta G_{max}$  obtained from the maximum free energy among all elementary steps of the minimum-energy pathway.

## Zero-point energy (ZPE) and entropy corrections (TS)

The entropies of the gaseous molecules were taken from the NIST Chemistry WebBook and the zero-point energy (ZPE) was calculated according to:

$$E_{ZPE} = \sum_{i=1}^{3N} \frac{hv_i}{2}$$

The entropy change for adsorbed intermediates was calculated within the harmonic approximation:

$$\Delta S_{ads}(0 \to T, P^0) = S_{vib} = \sum_{i=1}^{3N} \left[ \frac{N_A h v_i}{T(e^{h v_i / K_B T} - 1)} - R \ln(1 - e^{-h v_i / K_B T}) \right]$$

Where  $v_i$  is DFT-calculated normal-mode frequency for species of 3N degree of freedom

(*N*=number of atoms) adsorbed on B-Cu(100) surface,  $N_A$  is the Avogadro's constant (6.022 × 10<sup>23</sup> mol<sup>-1</sup>), *h* is the Planck's constant (6.626 × 10<sup>-34</sup>J s), and  $k_B$  is the Boltzmann constant (1.38 × 10<sup>-23</sup> JK<sup>-1</sup>), *R* is the ideal gas constant (8.314 J K<sup>-1</sup> mol<sup>-1</sup>), and *T* is the system temperature, and *T*=298K in this work.

The activation energy barrier ( $E_{\text{barrier}}$ ) for the C–C coupling was calculated according to the following formula

$$E_{\text{barrier}} = E_{\text{TS}} - E_{\text{IS}}$$

where  $E_{IS}$  and  $E_{TS}$  are the free energy and the energy of the initial state and the transition state, respectively.

Molecule	ZPE (eV)	TΔS (eV)
CO <sub>2</sub>	0.31	0.66
CO	0.13	0.61
H <sub>2</sub>	0.28	0.40
H <sub>2</sub> O	0.57	0.67
C <sub>2</sub> H <sub>4</sub>	1.36	0.71
C <sub>2</sub> H <sub>5</sub> OH	2.11	0.83

 Table S1. Free energy corrections for gas-phase species.

**Table S2.** Calculated the energy of DFT ( $E_{DFT}$ ), zero point energies (ZPE) and entropy (TS) of different adsorption species.

Figures	Adsorption	$E_{ m DFT}$	ZPE	TS
	Species	(eV)	(eV)	(eV)
	B-Cu(100)	-247.88		
	OCO*	-271.69	0.33	0.12
	OCOH*	-275.37	0.63	0.16
	CO*	-264.49	0.21	0.13
	CHO*	-267.91	0.48	0.14
Figure 3b	HCOH*	-271.29	0.79	0.11
	CH*	-260.68	0.35	0.05
	CH <sub>2</sub> *	-264.47	0.63	0.08
	CH <sub>3</sub> *	-268.43	0.93	0.13
	CH <sub>4</sub>	-272.13	1.21	0.31
	COCO*	-279.60	0.43	0.20
	CHOCO*	-283.45	0.71	0.21
	CHOCOH*	-287.40	1.03	0.22
	CH <sub>2</sub> OHCO*	-291.31	1.34	0.25
Figure 4c	CH <sub>2</sub> CO*	-280.72	0.91	0.15
	CH <sub>3</sub> CO*	-284.86	1.22	0.20
	CH <sub>3</sub> COH*	-288.07	1.51	0.24
	CH <sub>3</sub> CHOH*	-291.97	1.82	0.22
	CH <sub>3</sub> CH <sub>2</sub> OH*	-295.62	2.16	0.31
	CHOCO*	-282.94	0.69	0.20
	CHOCHO*	-287.04	1.01	0.22
	CH <sub>2</sub> OCHO*	-291.07	1.35	0.17
	CH <sub>2</sub> OHCHO*	-294.90	1.67	0.20
	CH <sub>2</sub> CHO*	-284.18	1.18	0.20
	CH <sub>2</sub> CH <sub>2</sub> O*	-288.28	1.52	0.14

Figure 4d	CH <sub>3</sub> CH <sub>2</sub> O*	-291.99	1.83	0.26
	CH <sub>2</sub> CH <sub>2</sub> OH*	-291.93	1.84	0.21
	CH <sub>2</sub> CH <sub>2</sub> *	-280.24	1.39	0.24
	CH <sub>3</sub> CH <sub>2</sub> OH*	-295.62	2.16	0.31
	2B-Cu(100)	-249.02	-	
	20CO*	-297.09	0.65	0.29
	2COOH*	-304.57	1.28	0.30
	2CO*	-282.51	0.44	0.22
	TS	-282.10	0.44	0.20
Figure 5a	COCO*	-282.45	0.45	0.18
	3B-Cu(100)	-249.96		
	30CO*	-322.31	0.98	0.41
	3COOH*	-333.54	1.91	0.51
	3CO*	-300.41	0.65	0.38
	TS	-300.24	0.71	0.21
	CO*+COCO*	-300.37	0.65	0.30
	2CO*	-282.51	0.44	0.22
Figure 5b	CO*+CHO*	-286.08	0.72	0.20
	TS	-285.61	0.65	0.29
	CHOCO*	-286.43	0.77	0.14
	3CO*	-300.41	0.65	0.38
	2CO*+CHO*	-304.02	0.93	0.35
	TS	-303.85	0.94	0.28
	CO*+CHOCO*	-304.50	0.99	0.23

Table S3. The Bader charge of the B, and the average Bader charge of nearby Cu atoms.

	<b>B-Cu(100)</b>	2B-Cu(100)	3B-Cu(100)
Cu	-0.13	-0.11	-0.10
В	0.36	0.30	0.32



**Figure S1**. Projected crystal orbital Hamilton population (–COHP) bonding analysis of CO adsorbed on (a) pristine Cu(100) and (b) B-Cu(100), and the corresponding integrated COHP (ICOHP) value.



Figure S2. Adsorption geometries and energies of CO\* and CHO\* on pristine Cu(100) and B-Cu(100).



**Figure S3.** Optimized geometry structures of the B atom dopants at the defect Cu(100) (**a**) surface and (**b**) subsurface. Blue arrow: diffusion of the B atom from the defect sites to the four-fold hollow site of Cu. Red arrow: B atom from the four-fold hollow site of Cu to the defect site.



Figure S4. Optimized geometric of various intermediates for CO<sub>2</sub> reduction to CH<sub>4</sub> on B-Cu(100).



**Figure S5.** Free energy diagram of  $CO_2$  reduction into  $CH_4$  on B-Cu(100) catalyst. Red lines represent a competitive reaction and product selectivity.



**Figure S6**. Adsorption structure and free energy diagrams for CO\*+CO<sub>2</sub> conversion to CO\*+CO\* on B-Cu(100).



Figure S7. Optimized structure of the selectivity between the C1 and C2 products on B-Cu(100).



**Figure S8.** The atomic configurations of the transition state for (a) CO–CO and (b) CHO–CO coupling processes on B-Cu(100).



Figure S9. Optimized geometric of various intermediates for the hydrogenation COCO\* into  $C_2H_5OH$  and CHOCO\* into  $C_2H_5OH$ .



**Figure S10**. Optimized geometric of various intermediates for CO<sub>2</sub>\* reduction to CO\* and two separated CO\* dimerization to COCO\* (CO\*–CO\* coupling), CO\* hydrogenation to CHO\* and CO\* with CHO\* dimerization to CHOCO\* (CHO\*–CO\* coupling) on 2B-Cu(100) and 3B-Cu(100).



**Figure S11**. Charge density difference of CO\* adsorbed on 2B-Cu(100) and 3B-Cu(100). The isosurface value is set to be 0.002  $e^{A^{-3}}$ . Yellow denotes electron accumulation and cyan denotes electron depletion.